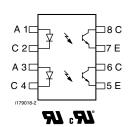
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Optocoupler, Phototransistor Output, Dual Channel, SOIC-8 Package





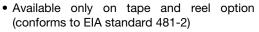
DESCRIPTION

The ILD205T, ILD206T, ILD207T, ILD211T, and ILD213T are optically coupled pairs with a gallium arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The ILD205T, ILD206T, ILD207T, ILD211T, and ILD213T come in a standard SOIC-8 small outline package for surface mounting which makes it ideally suited for high density applications with limited space. In addition to eliminating through-holes requirements, this package conforms to standards for surface mounted devices.

A specified minimum and maximum CTR allows a narrow tolerance in the electrical design of the adjacent circuits. The high BV_{CEO} of 70 V gives a higher safety margin compared to the industry standard of 30 V.

FEATURES

- Two channel coupler
- SOIC-8 surface mountable package
- Standard lead spacing of 0.05"





- Isolation test voltage, 4000 V_{RMS}
- Compatible with dual wave, vapor phase and IR reflow soldering
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- cUL file no. E52744, equivalent to CSA bulletin 5A

ORDERING INFORMATION							
	L D 2 # T				SIOC-8		
		PART NUMBER			6.1 mm		
AGENCY CERTIFIED/PACKAGE			CTR (%)				
AGENCY CERTIFIED/PACKAGE	10 mA						
UL, cUL	40 to 80	63 to 125	100 to 200	≥ 20	≥ 100		
SOIC-8	ILD205T	ILD206T	ILD207T	ILD211T	ILD213T		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER TEST CONDITION SYMBOL VALUE UNIT								
INPUT								
Peak reverse voltage		V_{R}	6	V				
Peak pulsed current	1 μs, 300 pps		1	Α				
Continuous forward current per channel		I _F	30	mA				
Power dissipation		P _{diss}	50	mW				



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
OUTPUT	·						
Collector emitter breakdown voltage		BV _{CEO}	70	V			
Emitter collector breakdown voltage		BV _{ECO}	7	V			
Power dissipation per channel		P _{diss}	125	mW			
COUPLER	·						
Isolation test voltage	t = 1 s	V _{ISO}	4000	V_{RMS}			
Total package dissipation ambient (2 LEDs and 2 detectors, 2 channels)		P _{tot}	350	mW			
Storage temperature		T _{stg}	-55 to +150	°C			
Operating temperature		T _{amb}	-55 to +100	°C			
Soldering time from 260 °C ⁽¹⁾		T _{sld}	10	S			

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	$I_F = 10 \text{ mA}$		V_{F}		1.2	1.55	V	
Reverse current	$V_R = 6 V$		I _R		0.1	100	μA	
Capacitance	$V_R = 0 V$		Co		25		pF	
OUTPUT								
Collector emitter breakdown voltage	$I_C = 10 \mu A$		BV _{CEO}	70			V	
Emitter collector breakdown voltage	I _E = 10 μA		BV _{ECO}	7			V	
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ A}$		I _{CEO}		5	50	nA	
Collector emitter capacitance	$V_{CE} = 0 V$		C _{CE}		10		pF	
COUPLER								
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V _{CEsat}			0.4	V	
Capacitance (input to output)			C _{IO}		0.5		pF	
Resistance (input to output)			R _{IO}		100		GΩ	

Note

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		ILD205T	CTR _{DC}	40		80	%	
		ILD206T CTR _{DC} 63		125	%			
DC current transfer ratio	$V_{CE} = 5 \text{ V}, I_{F} = 10 \text{ mA}$		CTR _{DC}	100		200	%	
		ILD211T	CTR _{DC}	20			%	
DC current transfer fatto		ILD213T	CTR _{DC}	100			%	
		ILD205T	CTR _{DC}	13	30		%	
	$V_{CE} = 5 \text{ V}, I_F = 1 \text{ mA}$	ILD206T	CTR _{DC}	22	45		%	
		ILD207T	CTR _{DC}	34	70		%	

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SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT	
Delay time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _d		3		μs	
Rise time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _r		3		μs	
Fall time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _f		4.7		μs	
Storage time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _s		0.3		μs	
Turn-on time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _{on}		6		μs	
Turn-off time	V_S = 5 V, I_C = 2 mA, R_L = 100 Ω , (see figure 1)	t _{off}		5		μs	
Turn-on time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω , (see figure 2)	t _{on}		3		μs	
Turn-off time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω , (see figure 2)	t _{off}		10		μs	

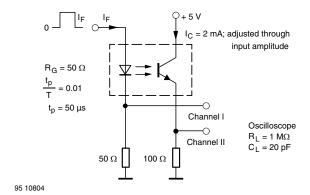


Fig. 1 - Test Circuit, Non-Saturated Operation

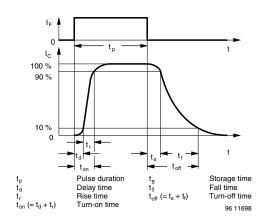


Fig. 3 - Switching Times

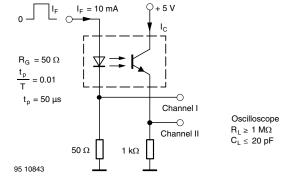


Fig. 2 - Test Circuit, Saturated Operation

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SAFETY AND INSULATION RATINGS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Climatic classification (according to IEC 68 part 1)				55/100/21				
Comparative tracking index		CTI	175		399			
V _{IOTM}			6000			V		
V _{IORM}			560			V		
P _{SO}					350	mW		
I _{SI}					150	mA		
T _{SI}					165	°C		
Creepage distance			4			mm		
Clearance distance			4			mm		
Insulation thickness			0.2			mm		

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

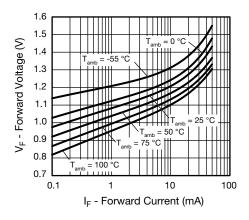


Fig. 4 - Forward Voltage vs. Forward Current

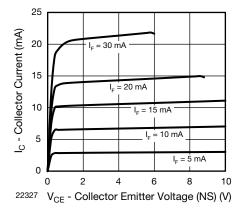


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

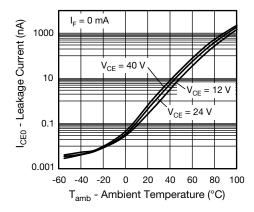


Fig. 6 - Leakage Current vs. Ambient Temperature

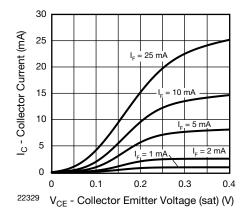


Fig. 7 - Collector Current vs. Collector Emitter Voltage (sat)

As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

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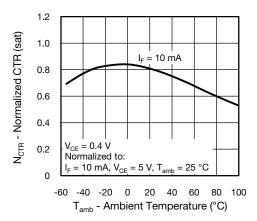


Fig. 8 - Normalized CTR (sat) vs. Ambient Temperature

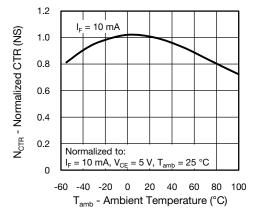


Fig. 9 - Normalized CTR (NS) vs. Ambient Temperature

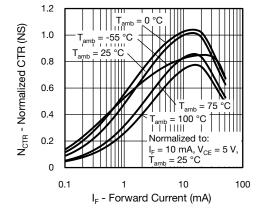


Fig. 10 - Normalized CTR (NS) vs. Forward Current

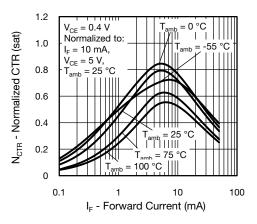


Fig. 11 - Normalized CTR (sat) vs. Forward Current

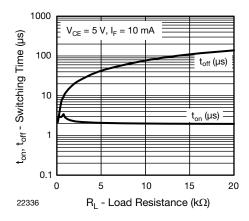


Fig. 12 - Switching Time vs. Load Resistance

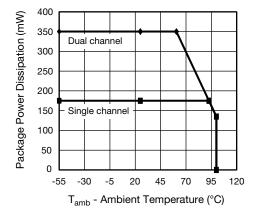
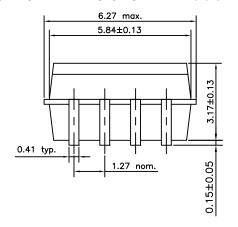


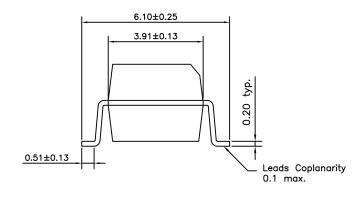
Fig. 13 - Power Dissipation vs. Ambient Temperature

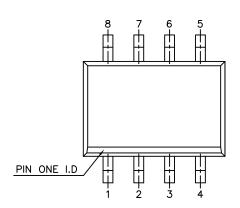


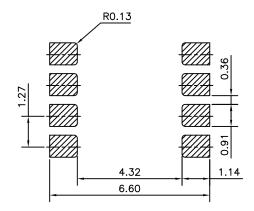
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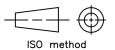
PACKAGE DIMENSIONS in millimeters











PACKAGE MARKING (Example)



Note

• Tape and reel suffix (T) is not part of the package marking.



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